



### BZT52C2V4LP - BZT52C39LP

#### SURFACE MOUNT ZENER DIODE

#### **Features**

- Ultra-Small Leadless Surface Mount Package
- Ideally Suited for Automated Assembly Processes
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Mechanical Data**

- Package: X1-DFN1006-2
- Package Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Marking Information
- Terminals: Finish NiPdAu over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Package	Packing		
Part Number	Fackage	Qty.	Carrier	
(Type Number)-7*	X1-DFN1006-2	3,000	Tape & Reel	
(Type Number)-7B**	X1-DFN1006-2	10,000	Tape & Reel	

<sup>\*</sup>Add "-7" to the appropriate type number in Electrical Characteristics Table. Example: 6.2V Zener = BZT52C6V2LP-7.

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

xx

Top View Bar Denotes Cathode Side xx = Product Type Marking Code (See Electrical Characteristics Table)

<sup>\*\*</sup>Add "-7" to the appropriate type number in Electrical Characteristics Table. Example: 6.2V Zener = BZT52C6V2LP-7B.



## **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Forward Voltage (Note 5)	@ $I_F = 10mA$	$V_{F}$	0.9	V

### **Thermal Characteristics**

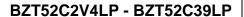
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6) $T_A = +25^{\circ}C$	$P_{D}$	250	mW
Thermal Resistance, Junction to Ambient Air	(Note 6) $T_A = +25^{\circ}C$	$R_{\theta JA}$	500	°C/W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-65 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Type Number	Marking Code	Zener Voltage Range (Note 5)			Maximum Zener Impedance f = 1kHz		Maximum Reverse Current (Note 5)		Temperature Coefficient @ I <sub>ZTC</sub> mV/°C		Test Current I <sub>ZTC</sub>		
			V <sub>Z</sub> @ I <sub>ZT</sub>		I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @ I <sub>ZK</sub>	Izk	I <sub>R</sub>	@ V <sub>R</sub>			
D7T5000\/41.D	14/1/	Nom (V)	Min (V)	Max (V)	mA	2		mA	μA	V	Min	Max	mA
BZT52C2V4LP	WX	2.4	2.20	2.60	5	100	600	1.0	50	1.0	-3.5	0	5
BZT52C2V7LP	W1	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0	5
BZT52C3V0LP	W2	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0	5
BZT52C3V3LP	W3	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0	5
BZT52C3V6LP	W4	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0	5
BZT52C3V9LP	W5	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V3LP	W6	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V7LP	W7	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2	5
BZT52C5V1LP	9Y	5.1	4.8	5.4	5	60	480	1.0	2.0	2.0	-2.7	1.2	5
BZT52C5V6LP	9A	5.6	5.2	6.0	5	40	400	1.0	1.0	2.0	-2	2.5	5
BZT52C6V2LP	9B	6.2	5.8	6.6	5	10	150	1.0	3.0	4.0	0.4	3.7	5
BZT52C6V8LP (Note 7)	9C	6.8	6.4	7.2	5	15	80	1.0	2.0	4.0	1.2	4.5	5
BZT52C7V5LP	9D	7.5	7.0	7.9	5	15	80	1.0	1.0	5.0	2.5	5.3	5
BZT52C8V2LP	9E	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2	5
BZT52C9V1LP	9F	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0	5
BZT52C10LP	9G	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0	5
BZT52C11LP	9H	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0	5
BZT52C12LP	9J	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0	5
BZT52C13LP	9K	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0	5
BZT52C15LP	9L	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13.0	5
BZT52C16LP	9M	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14.0	5
BZT52C18LP	9N	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16.0	5
BZT52C20LP	9P	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	-	5
BZT52C22LP	9R	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	-	5
BZT52C24LP	9S	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	-	5
BZT52C36LP	9W	36	34.0	38.0	2	90	350	0.5	0.1	25.2	36.5	-	5
BZT52C39LP	9X	39	37.0	41.0	2	130	350	0.5	0.1	27.3	36.8	-	5

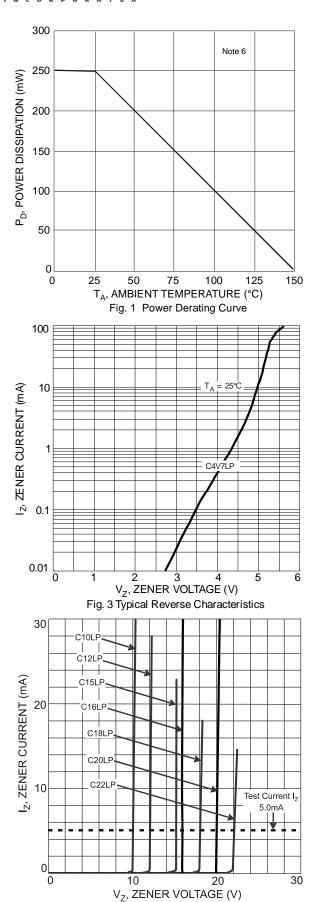
Notes:

- 5. Short duration pulse test used to minimize self-heating effect.
- 6. Device mounted on FR-4 PCB with minimum recommended pad layout, as shown in Diodes Incorporated's Suggested Pad Layout document, which can be found on our website at http://www.diodes.com.
- 7. Device can withstand a repetitive, 1A pulse with tp =  $300\mu$ s and T = 3s (forward or reverse direction).



1000





I<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (mA) 100 Γ<sub>A</sub>= -40°C 0.1 0 0.3 0.6 0.9 1.2 1.5 V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics 50 40 I2, ZENER CURRENT (mA) Test Current I 10 5 10 V<sub>Z</sub>, ZENER VOLTAGE (V)
Fig. 4 Typical Zener Breakdown Characteristics I<sub>2</sub>, ZENER CURRENT (mA) 20 40 50 V<sub>Z</sub>, ZENER VOLTAGE (V)

Fig. 6 Typical Zener Breakdown Characteristics

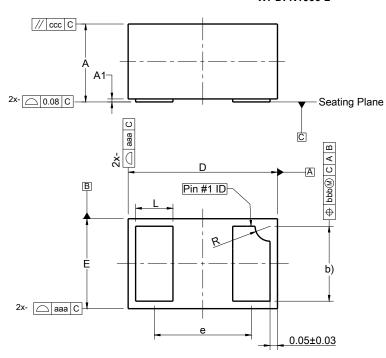
Fig. 5 Typical Zener Breakdown Characteristics



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X1-DFN1006-2

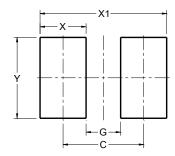


X1-DFN1006-2					
Dim	Min Max Ty		Тур		
Α	0.47	0.53	0.50		
A1	0.00	0.05	0.03		
b	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Е	0.55	0.675	0.60		
е	-		0.65		
١	0.20 0.30 0.25				
R	0.05 0.15 0.10				
aaa	aaa 0.15				
bbb	0.05				
CCC	0.05				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X1-DFN1006-2



Dimensions	Value		
Dillielisions	(in mm)		
С	0.70		
G	0.30		
Х	0.40		
X1	1.10		
Υ	0.70		



#### **IMPORTANT NOTICE**

- 1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- 5. Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
- 9. This Notice may be periodically updated with the most recent version available at <a href="https://www.diodes.com/about/company/terms-and-conditions/important-notice">https://www.diodes.com/about/company/terms-and-conditions/important-notice</a>

DIODES is a trademark of Diodes Incorporated in the United States and other countries. The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. © 2022 Diodes Incorporated. All Rights Reserved.

www.diodes.com